NSN 5961-00-478-7617

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Inclosure Material:

Metal

Overall Length:

0.535 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.865 inches

Thread Size:

0.312 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage, dc and 300.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

20.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

96214-535247 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

